SCAS031C - JULY 1987 - REVISED APRIL 1996

A8 [] 12

3-State Outputs Drive Bus Lines Directly DB, DW, NT, OR PW PACKAGE (TOP VIEW) inputs Are TTL-Voltage Compatible Flow-Through Architecture Optimizes 24 DIR A1 🛛 **PCB Lavout** A2 🛮 2 23 B1 Center-Pin V_{CC} and GND Configurations A3 🛮 3 22 B2 Minimize High-Speed Switching Noise 21 B3 A4 🛮 4 20 T B4 EPIC™ (Enhanced-Performance Implanted GND [5 GND 6 CMOS) 1-um Process 19 V_{CC} 18 VCC GND 7 500-mA Typical Latch-Up Immunity at GND 8 17 B5 125°C A5 1 9 16 N B6 Package Options Include Plastic A6 1 10 15 B7 Small-Outline (DW), Shrink Small-Outline A7 11 14 B8 (DB), and Thin Shrink Small-Outline (PW) 13) OE

description

DIPs (NT)

The octal bus transceiver is designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

The device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so that the buses are effectively isolated.

The 74ACT11245 is characterized for operation from -40°C to 85°C.

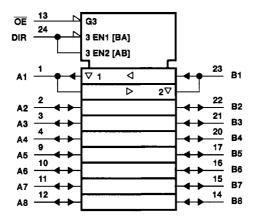
Packages, and Standard Plastic 300-mil

FUNCTION TABLE

	OUTPUT ENABLE OE	DIRECTION CONTROL DIR	OUTPUT						
	L	L	B data to A bus						
	L	н	A data to B bus						
	н	x	Isolation						

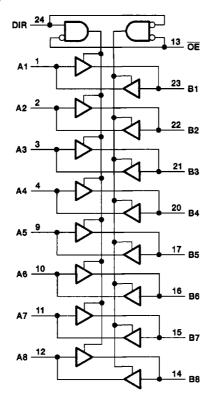
EPIC is a trademark of Texas Instruments Incorporated

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Output voltage range, VO (see Note 1)	0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, IO (VO = 0 to VCC)	±50 mA
Continuous current through V _{CC} or GND	
Maximum power dissipation at T _A = 55°C (in still air) (see Note 2	2): DB package 0.65 W
	DW package
	NT package
	PW package 0.7 W
Storage temperature range, T _{sto}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the NT package, which has a trace length of zero.

recommended operating conditions

		MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		٧
V _{IL}	Low-level input voltage		8.0	٧
VI	input voltage	0	Vcc	٧
Vo	Output voltage	0	VCC	٧
1 _{ОН}	High-level output current		-24	mA
lol	Low-level output current		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
TA	Operating free-air temperature	-40	85	ů



74ACT11245 OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCAS031C - JULY 1987 - REVISED APRIL 1996

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DA	DANSTED	TEST CONDITIONS	Vcc	T _A = 25°C			MIN	MAX	UNIT
PARAMETER		TEST CONDITIONS		MIN	TYP	MAX			
		I _{OH} = -50 μA	4.5 V	4.4	_		4.4		V
			5.5 V	5.4			5.4		
VOH			4.5 V	3.94			3.8		
		IOH = -24 mA		4.94			4.8		
		IOH = -75 mA†	5.5 V				3.85		
		I 50 A	4.5 V		-	0.1 0.1			
		IOL = 50 μA	5.5 V			0.1		0.1	٧
VOL		In. DAMA	4.5 V			0.36		0.44	
		IOL = 24 mA	5.5 V			0.36		0.44	
		I _{OL} = 75 mA [†]	5.5 V					1.65	
loz	A or B ports‡	VO = VCC or GND	5.5 V			±0.5		±5	μA
lį.	OE or DIR	V _I = V _{CC} or GND	5.5 V			±0.1		±1	μΑ
lcc		VI = VCC or GND, IO = 0	5.5 V			8		80	μА
ΔICC§		One input at 3.4 V, Other inputs at GND or V _{CC}	5.5 V			0.9		1	mA
Ci		V _I = V _{CC} or GND	5 V		4				рF
Co		VO = VCC or GND	5 V		12				pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recomended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 25°C			MIN	MAX	UNIT
PARAMETER			MIN	TYP	MAX	MILIT	MIMA	UNII
tPLH	A or B	B or A	1.5	6.2	9.2	1.5	10	ns
t _{PHL}	A OF B		1.5	5.4	8.6	1.5	9.1	
^t PZH	ŌĒ	A or B	1.5	8.1	12	1.5	13.2	ns l
tPZL	OE		1.5	8.2	11.7	1.5	12.9	
tPHZ	ŌĒ	A or B	1.5	9.3	11.8	1.5	12.9	200
^t PLZ]	A U/ B	1.5	9.8	12.9	1.5	13.9	ns

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER			TEST CO	TYP	UNIT	
C _{pd}	Davies dissination conscitous and transcripes	Outputs enabled	C. F0-F	f = 1 MHz	66	
	Power dissipation capacitance per transceiver	Outputs disabled	Cլ = 50 pF,		19	pF

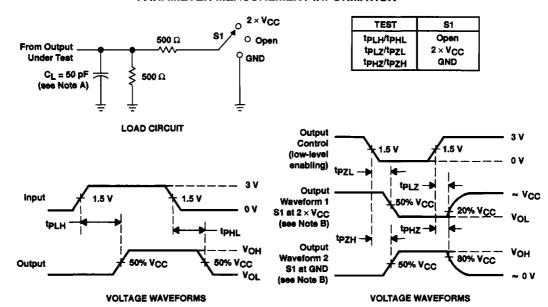


[‡] For I/O ports, the parameter IOZ includes the input leakage current.

⁹ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

SCAS031C - JULY 1987 - REVISED APRIL 1996

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_{O} = 50 Ω , t_{f} = 3 ns, t_{f} = 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms